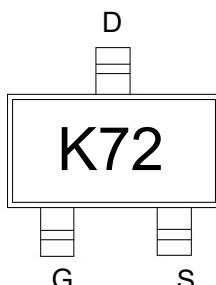


## Features

- Trench Power MV MOSFET technology
- Voltage controlled small signal switch
- Low input Capacitance
- Fast Switching Speed
- Low Input / Output Leakage

## Application

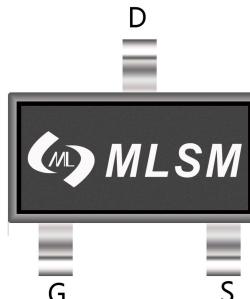
- Load Switch for Portable Devices
- DC/DC Converter



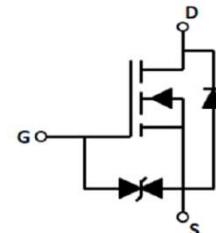
K72: Device code

## Product Summary

V <sub>DS</sub>	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> MAX
60V	2.5Ω@10V	0.34A
	3.0Ω@4.5V	



SOT-523 top view



Schematic diagram

Marking and pin assignment



Halogen-Free

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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## Common Ratings (TC=25°C Unless Otherwise Noted)

V <sub>DS</sub>	Drain-Source Breakdown Voltage	60	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
T <sub>J</sub>	Maximum Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature Range	-50 to 155	°C
I <sub>S</sub>	Diode Continuous Forward Current	Tc=25°C 0.34	A

## Mounted on Large Heat Sink

I <sub>DM</sub>	Pulse Drain Current Tested	Tc=25°C 1.2	A
I <sub>D</sub>	Continuous Drain Current	Tc=25°C 0.34	A
P <sub>D</sub>	Maximum Power Dissipation	Tc=25°C 0.35	W
R <sub>θJA</sub>	Thermal Resistance Junction-to-Ambient	357	°C/W

## Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
2N7002KT	SOT-523	K72	3,000	45,000	180,000	7" reel

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	60	--	--	V
I <sub>bss</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	--	--	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±10	μA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.0	1.6	2.5	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =0.5A	--	1.6	2.5	Ω
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =0.2A	--	2.1	3.0	Ω
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V, f=1MHz	--	21	--	pF
C <sub>OSS</sub>	Output Capacitance		--	9	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	4	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =30V, I <sub>D</sub> =0.3A, V <sub>GS</sub> =10V	--	1.22	2.4	nC
Q <sub>gs</sub>	Gate-Source Charge		--	0.5	--	nC
Q <sub>gd</sub>	Gate-Drain Charge		--	0.18	--	nC
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>GS</sub> =0V, I <sub>S</sub> =300mA, V <sub>R</sub> =25V, di/dt=100A/μs	--	3.6	--	nC
t <sub>rr</sub>	Reverse recovery Time		--	16	--	nS
t <sub>D(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =50V, I <sub>D</sub> =200mA, V <sub>GS</sub> =10V, R <sub>G</sub> =50Ω	--	7	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	19	--	nS
t <sub>D(off)</sub>	Turn-Off Delay Time		--	20	--	nS
t <sub>f</sub>	Turn-off fall Time		--	84	--	nS
<b>Source-Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>J</sub> =25°C, I <sub>S</sub> =0.34A	--	--	1.2	V

### Typical Operating Characteristics

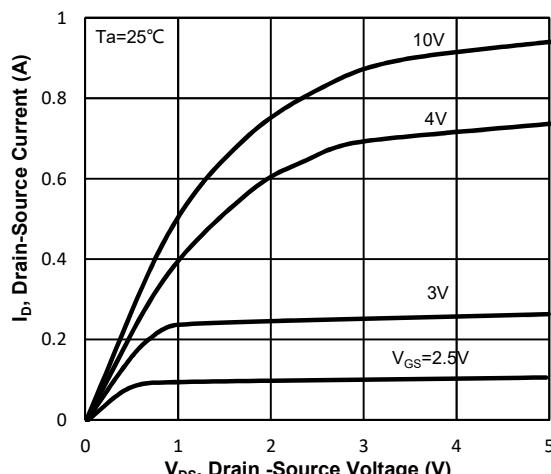


Fig1. Typical Output Characteristics

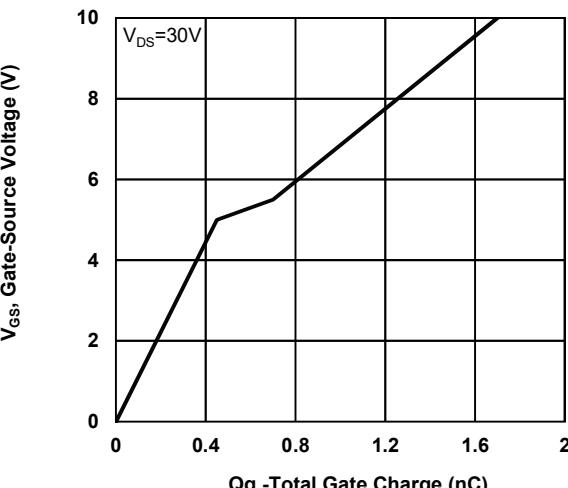


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

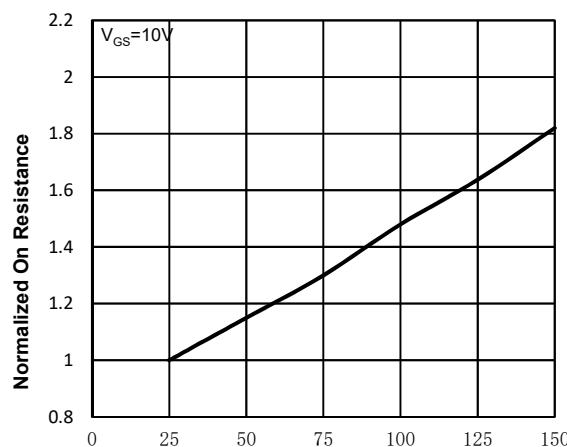


Fig3. Normalized On-Resistance Vs. Temperature

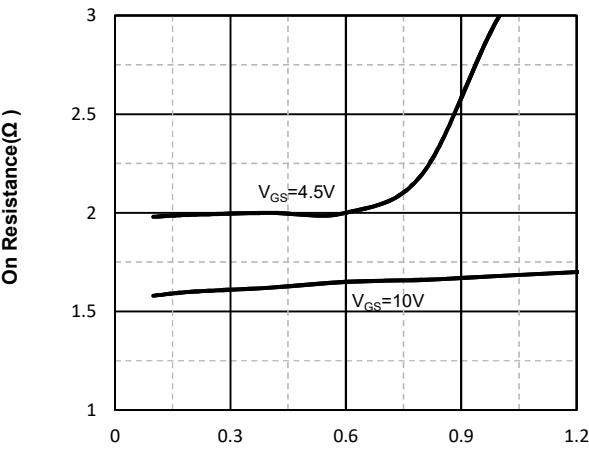


Fig4. On-Resistance Vs. Drain-Source Current

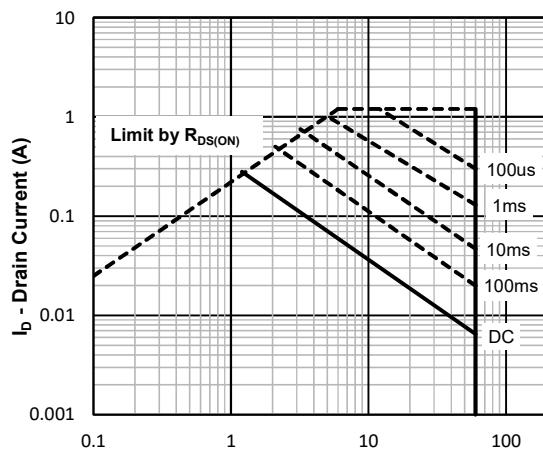


Fig5. Maximum Safe Operating Area

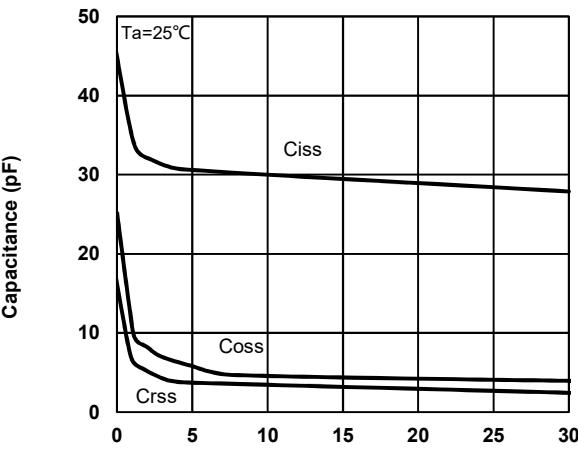
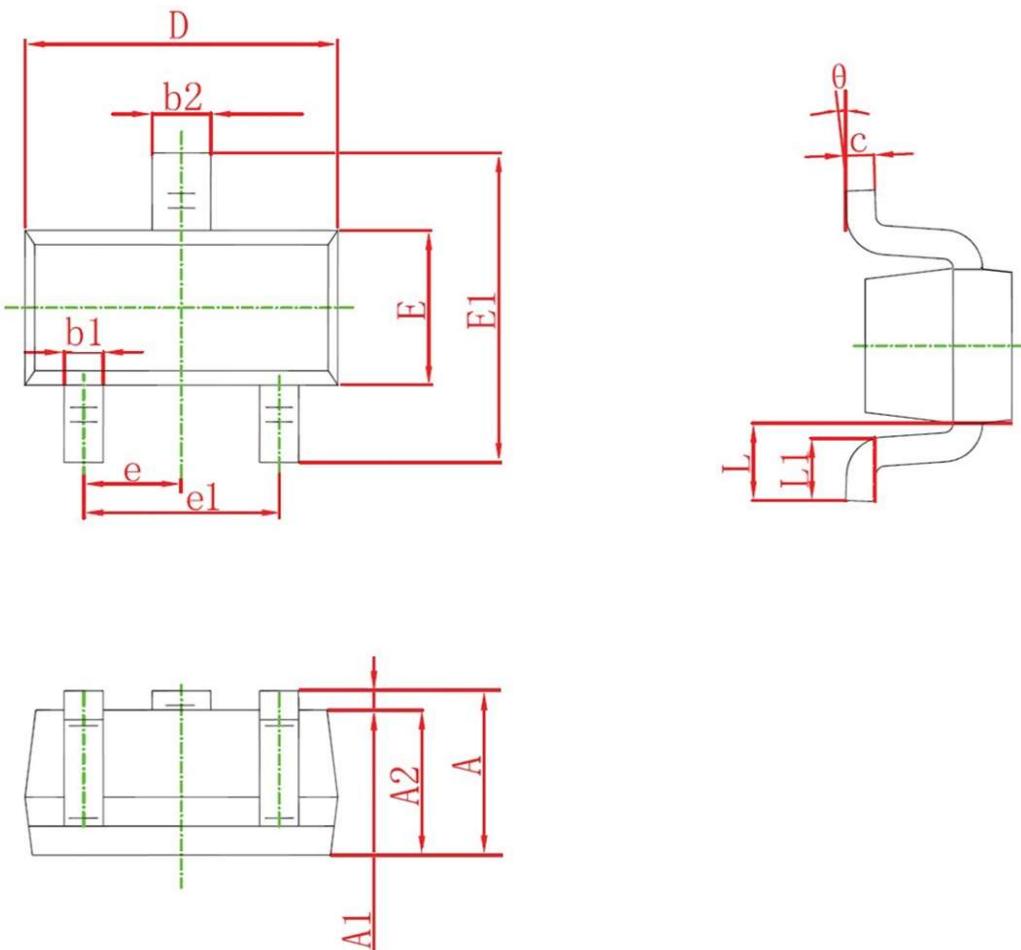


Fig6. Typical Capacitance Vs.Drain-Source Voltage

## SOT-523 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500TYP		0.020TYP	
e1	0.900	1.100	0.035	0.043
L	0.400REF		0.016REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°